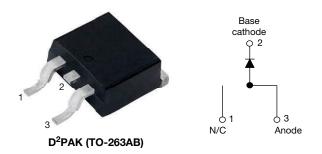
VS-12TQ035S-M3, VS-12TQ040S-M3, VS-12TQ045S-M3

**Vishay Semiconductors** 

## High Performance Schottky Rectifier, 15 A



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PRIMARY CHARACTERISTICS							
I <sub>F(AV)</sub>	15 A						
V <sub>R</sub>	35 V, 40 V, 45 V						
V <sub>F</sub> at I <sub>F</sub>	0.50 V						
I <sub>RM</sub> typ.	70 mA at 125 °C						
T <sub>J</sub> max.	150 °C						
E <sub>AS</sub>	16 mJ						
Package	D <sup>2</sup> PAK (TO-263AB)						
Circuit configuration	Single						

#### FEATURES

- 150 °C T<sub>J</sub> operation
- Very low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### DESCRIPTION

The VS-12TQ...S-M3 Schottky rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS VALUES								
I <sub>F(AV)</sub>	Rectangular waveform	15	A						
V <sub>RRM</sub>	Range	35 to 45	V						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	990	A						
V <sub>F</sub>	15 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.50	V						
Тј	Range	-55 to +150	°C						

VOLTAGE RATINGS								
PARAMETER SYMBOL VS-12TQ035S-M3 VS-12TQ040S-M3 VS-12TQ045S-M3 UN								
Maximum DC reverse voltage	V <sub>R</sub>	35	40	45	V			
Maximum working peak reverse voltage	V <sub>RWM</sub>	55	40	45	v			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDI	TEST CONDITIONS					
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at $T_C = 120$ °C	15	A				
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated	990	А			
non-repetitive surge current See fig. 7	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	load condition and with rated V <sub>RRM</sub> applied	250				
Non-repetitive avalanche energy	E <sub>AS</sub>	$T_J = 25 \text{ °C}, I_{AS} = 2.4 \text{ A}, L = 5.5 \text{ r}$	16	mJ				
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		2.4	А			

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HALOGEN

FREE

### VS-12TQ035S-M3, VS-12TQ040S-M3, VS-12TQ045S-M3

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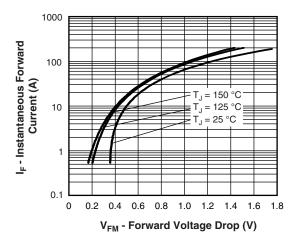
ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
Maximum forward voltage drop See fig. 1		15 A	– T <sub>.1</sub> = 25 °C	0.56				
	V <sub>FM</sub> <sup>(1)</sup>	30 A	$1_{\rm J} = 25$ C	0.71	v			
	VFM \''	15 A	− T,ı = 125 °C	0.50				
		30 A	- IJ = 125 C	0.64				
Maximum reverse leakage current	I <sub>BM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	1.75	mA			
Maximum reverse leakage current	IRM \''	T <sub>J</sub> = 125 °C	V <sub>R</sub> = naleu V <sub>R</sub>	110	ШA			
Typical reverse leakage current	ypical reverse leakage current I <sub>RM</sub> <sup>(1)</sup> T		V <sub>R</sub> = Rated V <sub>R</sub>	70	mA			
Maximum junction capacitance	$C_T$ $V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °		nge 100 kHz to 1 MHz), 25 °C	900	pF			
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs				

Note

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 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +150	°C			
Maximum thermal resistance, junction to case		R <sub>thJC</sub>	DC operation See fig. 4	2.0				
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	°C/W			
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torque	minimum			6 (5)	kgf · cm			
Mounting torque	maximum			12 (10)	(lbf ⋅ in)			
Marking device			Case style D <sup>2</sup> PAK (TO-263AB)	12TQ 12TQ 12TQ	044S			





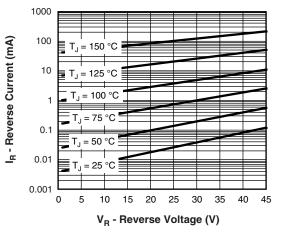


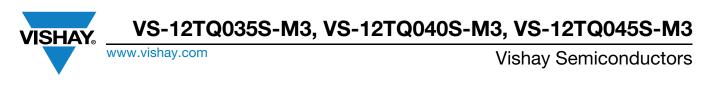
Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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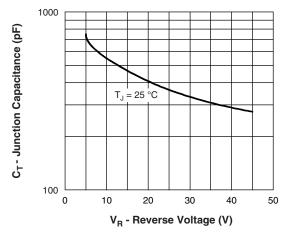


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

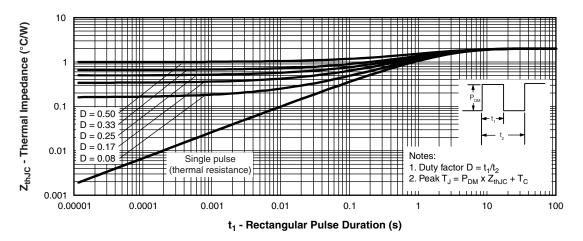


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

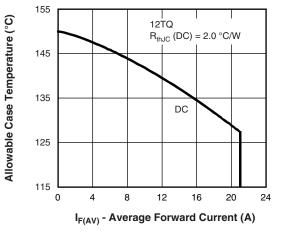


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

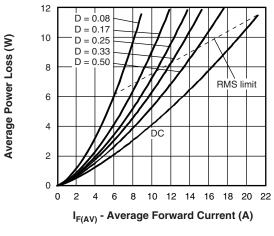


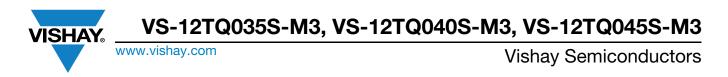
Fig. 6 - Forward Power Loss Characteristics

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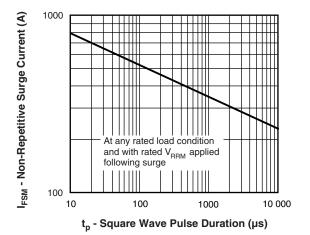


Fig. 7 - Maximum Non-Repetitive Surge Current

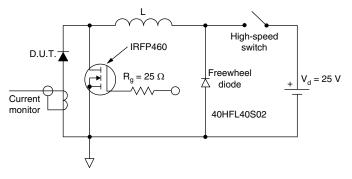


Fig. 8 - Unclamped Inductive Test Circuit

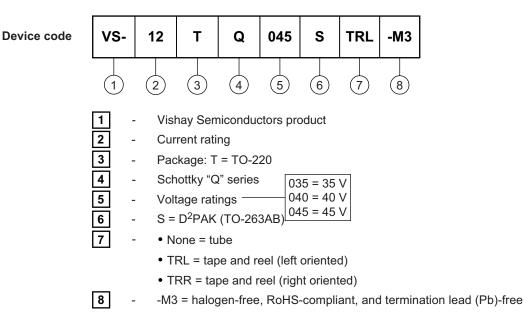
VS-12TQ035S-M3, VS-12TQ040S-M3, VS-12TQ045S-M3



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### **ORDERING INFORMATION TABLE**

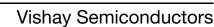
SHAY



ORDERING INFORMATION							
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION					
VS-12TQ035S-M3	50	Antistatic plastic tubes					
VS-12TQ035STRL-M3	800	13" diameter plastic tape and reel					
VS-12TQ035STRR-M3	800	13" diameter plastic tape and reel					
VS-12TQ040S-M3	50	Antistatic plastic tubes					
VS-12TQ040STRL-M3	800	13" diameter plastic tape and reel					
VS-12TQ040STRR-M3	800	13" diameter plastic tape and reel					
VS-12TQ045S-M3	50	Antistatic plastic tubes					
VS-12TQ045STRL-M3	800	13" diameter plastic tape and reel					
VS-12TQ045STRR-M3	800	13" diameter plastic tape and reel					

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?96164					
Part marking information	www.vishay.com/doc?95444					
Packaging information	www.vishay.com/doc?96424					

# **Outline Dimensions**

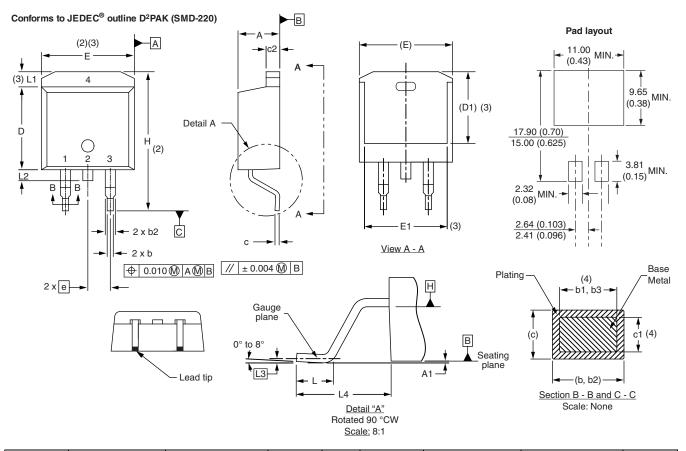


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D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches

SHA



SYMBOL	MILLIMETERS		INC	INCHES		NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	) BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Datum A and B to be determined at datum plane H

<sup>(6)</sup> Controlling dimension: inch

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

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